

General purpose (dual digital transistors)

EMB10 / UMB10N / IMB10A

●Features

- 1) Two DTA123J chips in a EMT or UMT or SMT package.
- 2) Mounting possible with EMT3 or UMT3 or SMT3 automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.
- 4) Mounting cost and area can be cut in half.

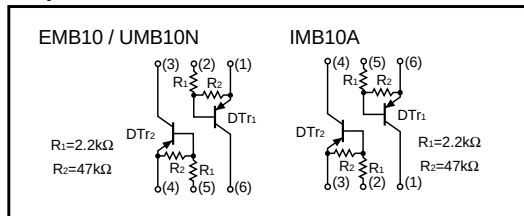
●Structure

Epitaxial planar type

PNP silicon transistor (Built-in resistor type)

The following characteristics apply to both DTr1 and DTr2.

●Equivalent circuit



●Absolute maximum ratings (Ta = 25°C)

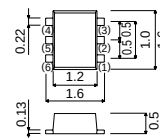
Parameter	Symbol	Limits	Unit
Supply voltage	V _{CC}	-50	V
Input voltage	V _{IN}	-12 5	V
Output current	I _O I _{C (Max.)}	-100 -100	mA
Power dissipation	Pd	150 (TOTAL)	*1 mW
		300 (TOTAL)	*2 mW
Junction temperature	T _J	150	°C
Storage temperature	T _{stg}	-55~+150	°C

*1 120mW per element must not be exceeded.

*2 200mW per element must not be exceeded.

●External dimensions (Units : mm)

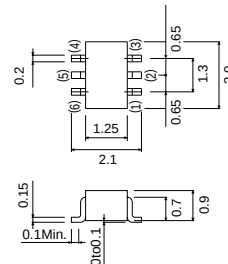
EMB10



Each lead has same dimensions

ROHM : EMT6 Abbreviated symbol : B10

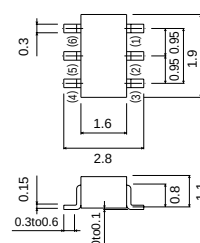
UMB10N



Each lead has same dimensions

ROHM : UMT6
EIAJ : SC-88 Abbreviated symbol : B10

IMB10A



Each lead has same dimensions

ROHM : SMT6
EIAJ : SC-74 Abbreviated symbol : B10

Transistors

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{i(off)}$	—	—	-0.5	V	$V_{CC} = -5V, I_o = -100\mu A$
	$V_{i(on)}$	-1.1	—	—	—	$V_o = -0.3V, I_o = -5mA$
Output voltage	$V_o(on)$	—	-0.1	-0.3	V	$I_o/I_i = -5mA/-0.25mA$
Input current	I_i	—	—	-3.6	mA	$V_i = -5V$
Output current	$I_o(off)$	—	—	-0.5	μA	$V_{CC} = -50V, V_i = 0V$
DC current gain	G_i	80	—	—	—	$V_o = -5V, I_o = -10mA$
Transition frequency	f_T	—	250	—	MHz	$V_{CE} = -10mA, I_E = 5mA, f = 100MHz$ *
Input resistance	R_i	1.54	2.2	2.86	$k\Omega$	—
Resistance ratio	R_2 / R_1	17	21	26	—	—

* Transition frequency of the device

●Packaging specifications

Type	Package	Taping		
	Code	T2R	TR	T148
	Basic ordering unit (pieces)	8000	3000	3000
EMB10		○	—	—
UMB10N		—	○	—
IMB10A		—	—	○

●Electrical characteristic curves

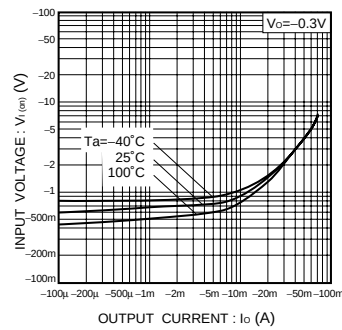


Fig.1 Input voltage vs. output current (ON characteristics)

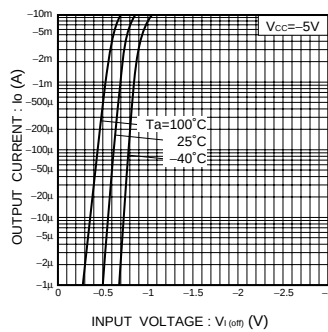


Fig.2 Output current vs. input voltage (OFF characteristics)

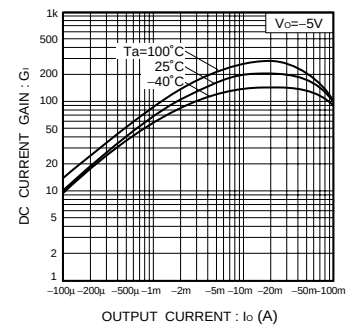


Fig.3 DC current gain vs. output current

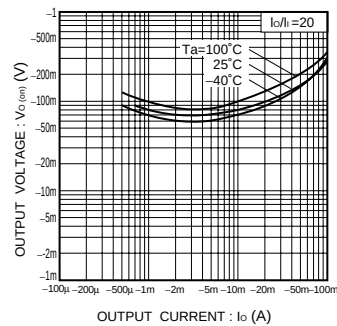


Fig.4 Output voltage vs. output current